



Vanadium in strongly correlated electron system $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$: Paradoxically boosted de NO_x reaction under SO_x environment via modulating electron correlation



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ABSTRACT

The persistent challenge of NO_x selective catalytic reduction degradation in the presence of SO_x has remained unresolved for decades. In this study, we report a paradoxical boosted denitration performance more than 20% under the SO_x environment through controlling the charge state of V utilizing strongly correlated electron systems (SCES) in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. Substitutional doped V at the Ni site, and the computed charge gap from DFT confirms the SCES. Through the manipulation of the strong correlation between V and Ni, V preserves the between + 2–3 charge state in the presence of SO_x . Furthermore, we achieved a stable oxidation/reduction cycle and higher denitration efficiency by altering the oxidation point of $(\text{NH}_4)\text{HSO}_4$ -contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. This results from deliberate decrease in Coulombic repulsion between Ni and V, improving electron transfer for catalytic performance. This revelation offers a resolution of exceptional denitration performance within SO_x in industrial exhaust systems, exploiting the foundational principles of SCES.

1. Introduction

The utilization of selective catalytic reduction (SCR) has become prevalent in the mitigation of nitrogen oxide (NO_x) emissions from exhaust systems in thermal power plants and internal combustion engines. By employing urea ($\text{CO}(\text{NH}_2)_2$) or ammonia (NH_3), NO_x is converted to nitrogen (N_2) and water (H_2O) on metal oxide (MO) catalysts like V_2O_5 , achieved through modulation of valence states between V^{+2}

and V^{+5} . Therefore, numerous studies have delved into strategies to enhance SCR efficiency, encompassing catalyst doping, pore size modulation, and surface modifications to maximize NH_3 and NO_x adsorption on MO catalysts [1–7]. However, the enduring challenge of NO_x selective catalytic reduction degradation in the presence of sulfur oxides (SO_x), inevitably stemming from fossil fuel combustion, has remained unsolved [2]. The deposition of ammonium bisulfates salt (ABS, $(\text{NH}_4)\text{HSO}_4$) due to $\text{NH}_3\text{-SO}_x$ interactions on the catalyst obstructs acid sites,

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leading to disruption of the reduction/oxidation cycle and a significant reduction in deNO_x efficiency. In addition, synthesized ABS physically obstructs the catalyst surface [1,8]. Despite decades of extensive efforts to enhance SO_x tolerance, the degradation of deNO_x performance continues to persist. Hence, alternative perspectives are imperative. Several proposed solutions have suggested mitigating the impact of SO_x on SCR catalysts through diverse approaches, including enhancing catalyst stability via optimized supports, combining various catalytic materials, exploring alternative catalytic substances, customizing exhaust gas decreasing systems, acid site control, sulfation, and adding purifying process under higher temperatures [8–18]. Given these extensive efforts, overcoming these limitations requires a different vantage point. From the research findings, we have gleaned insights into the potential of non-overlapping cation oxidation states or the inhibition of metal sulfates, even when they are enveloped by ABS, suggesting the achievement of a stable catalytic cycle beyond the conventional MO behavior. As a result, our focus lies on intriguing materials with high barriers to carrier transfer and the exposure of *d*-electron cation catalyst sites differing from the activated catalytic site of weaker oxygen bonding in V₂O₅.

In this context, we embrace the concept of strongly correlated electron systems (SCES) insulators, characterized by strong Coulombic repulsion between electrons in cations, resulting in manifold degrees of freedom arising from electron correlations and yielding tailor-made electronic, magnetic, and optical properties [19,20]. These interactions, which amalgamate electron-electron repulsion and principles of quantum mechanics, serve as the foundation for magnetic order an aspect of significant technological and physical relevance. The pronounced strong Coulombic repulsion facilitates carrier transfer via hopping of localized (*d* or *f*-orbital) electrons between nearest cations described as iⁿjⁿ → iⁿ⁻¹jⁿ⁺¹ (i and j are different cations). Consequently, the diverse mechanisms of carrier transfer in SCES insulators, as opposed to conventional transition metal oxide (iⁿOⁿ → iⁿ⁺¹Oⁿ⁻¹, where i and O are the cation and oxygen), demonstrate the prospective application of various fields by modifying crystal structure and composition via the tuning of Coulomb repulsion between *d* electron cations [21–24]. In SCES catalysts, the weakening of the electron correlations induced enhancements in conductivity, thereby improving charge transfer at catalyst-product interfaces to elevate the performance of catalysts [19,25–28]. This motivates the modulation of SCES correlation control through strategies such as applying strain to the matrix or distorting the crystal structure via compositional doping, all in the pursuit of catalytic site activation.

In this study, we aim to enhance electron transfer between nearest cations to activate catalytic sites, particularly when lower correlations between cations are obstructed by ABS on V-doped NiWO₄ SCES insulators. The NiWO₄ SCES insulator features a monoclinic structure with lower symmetry than cubic NiO, offering an additional degree of freedom compared to binary SCES insulators. It features approximately 4 Å of vacant space within its crystal lattice. The substitutionally doped V is located at the [NiO₆] octahedral site, mirroring the + 2.x persistent valence state of V and associated with the Coulombic repulsion of Ni. The V atoms within the NiWO₄ SCES matrix emerge SCR activity due to the diluted electron correlation of each magnetic cation within uncontaminated environments. Simultaneously, elevated SCR performance is observed when the surface of Ni_{1-x}V_xWO₄ (x = 0.05, 0.1) is tainted by ABS. The V dopant maintains its + 2.α valence state due to sustained electron correlation with Ni. However, heightened carrier transfer transpires under ABS-induced strong acidification, driven by higher electron/hole pair as Ni^{+2,α}V^{+2,α} → Ni^{+2,α-γ}V^{+2,α+δ}, promoting an enhanced exchange of carriers between NH₃ gas and higher adsorption on Ni_{1-x}V_xWO₄ surfaces. Furthermore, the creation of oxidation sites generates a sustainable reduction/oxidation cycle, contributing to stable catalytic activity. This process, in turn, leads to boosted deNO_x performance in the presence of SO_x on SCES oxide of Ni_{1-x}V_xWO₄. The paradoxically elevated catalytic efficiency observed on ABS-contaminated surfaces, achieved through tuning electron correlation, introduces an

unprecedented solution for advanced SCR catalysts – a field that has hitherto been hindered by inescapable atmospheric conditions.

2. Experiment section

2.1. Synthesize the sample and structure analysis

The NiWO₄, V_{0.05}Ni_{0.95}WO₄, and V_{0.1}Ni_{0.9}WO₄ powders were synthesized by solid-state reactions. The metal oxide powders, NiO, WO₃, and V₂O₅, were mixed following the stoichiometric ratios of each composition. Subsequently, a calcination process was carried out in an electric furnace at 700 °C for 12 h. Additionally, the fabrication of ABS-contaminated samples involved combining 10 wt% of ABS with DI water. After drying the mixture was overnight in an oven, heat treatment at 100 °C for 3 h was administered. Crystal structure analysis of synthesized powder was conducted using X-ray diffractometer (XRD) and Fourier transform infrared (FT-IR) spectroscopy. The XRD results were obtained using the Rigaku Smartlab system, recording spectra with the angular (2θ) range of 20 – 80 degrees by via Kα1 radiation of copper (λ = 1.54059 Å). The detailed structures were refined using GSAS-2, and the resulting crystal structures were visualized using VESTA. [29,30] Polarity and dipole vibration mode measurements were acquired via FT-IR spectroscopy (Vertex 70, Bruker, United States). Subsequently, a comprehensive analysis of the microstructure and morphology was performed using scanning electron microscopy (SEM, JEOL JSM-7001 F, Japan) operating at an acceleration potential of 17 kV. Elemental mapping was accomplished through the utilization of energy-dispersive X-ray spectroscopy (EDS).

2.2. Measurement of physical and chemical characteristics

The optical band gap was determined using ultraviolet-visible and near-infrared diffuse reflectance spectroscopy (UV–VIS–NIR DRS, Cary5000, Agilent Technologies, United States). Magnetic properties were characterized using superconducting quantum interference device vibrating sample magnetometer (SQUID-VSM, Quantum Design). Elemental oxidation states were elucidated through X-ray photoelectron spectroscopy (XPS, K-alpha, Thermo Fisher Scientific, United States). Impedance measurements were conducted using potentiostat (VSP potentiostat, Bio-logic). For temperature-programmed experiments, including reduction (TPR), desorption (TPD), and oxidation (TPO), were conducted using an AutoChem II 2920 (Micromeritics Instrument Corp., USA). Prior to TPR/TPO measurements, a heat treatment step at 200 °C for 30 min was employed to eliminate H₂O and NH₃ absorption. TPD measurements were conducted at 50 °C for 60 min. The purging process was carried out at 50 °C for 1 h, followed by Ar purging for another 1 h.

2.3. Calculation of electronic structure

First-principles density functional theory (DFT) calculations were conducted utilizing the projector-augmented-wave method, employing the Perdew–Burke–Ernzerhof functional as implemented in the Vienna Ab initio simulation program (VASP) code [31–33]. The valence electrons employed in the calculations encompassed the 3d and 4s electrons of Ni, 5d and 6s electrons of W, 2s and 2p electrons of O, and 3d and 4s electrons of V. To capture the effects of localized electrons, an on-site Coulomb interaction was incorporated, utilizing a simplified rotationally invariant approach [34]. The Coulomb *U* and exchange *J* parameters, *U*_{eff} = *U* – *J*, and a value of 5.3 eV were chosen for the Ni 3d and V 3d orbitals [35,36]. A plane-wave basis cut-off energy of 800 eV was employed. For the partial substitution of V on the Ni site, a supercell with dimensions of *a* × *b* × 2*c* was employed. The *k*-point meshes adopted were 2 × 4 × 4 and 2 × 4 × 2 for the unit cell and supercell, respectively. Structural relaxation was conducted iteratively until the Hellmann–Feynman forces reached a convergence threshold of less than 1 × 10⁻³ eV Å⁻¹.

2.4. Catalytic activity evaluation

The fixed bed deNO_x performance assessment was executed by KITECH. The catalytic performance was evaluated in a fixed-bed reactor under atmospheric pressure. The operating temperature varied from 100 °C to 300 °C, and measurements were conducted for 40 min per data point. The reactive gas consisted 500 ppm of NO_x, NH₃, 100 ppm of SO_x, and 10 vol% of O₂, with the remaining balance being N₂, at a total flow rate of 500 sccm. For the evaluation, 0.35 mg of powdered catalyst was prepared, resulting in a gas hourly space velocity (GHSV) of 60,000 h⁻¹. Reactive gas concentrations were continuously monitored using FTIR spectroscopy (CX-4000; Gasmet Technologies, Vantaa, Finland) and an O₂ analyzer (Oxitec 5000; ENOTEC, Marienheide, Germany).

The NO_x conversion and N₂ selectivity were calculated in terms of the following formulas

$$\text{NO}_x \text{ conversion}(\%) = \frac{[\text{NO}]_{\text{in}} - [\text{NO}]_{\text{out}}}{[\text{NO}]_{\text{in}}} \times 100$$

$$\text{N}_2 \text{ selectivity}(\%) = \frac{[\text{NO}]_{\text{in}} - [\text{NO}]_{\text{out}} + [\text{NH}_3]_{\text{in}} - [\text{NH}_3]_{\text{out}} - [\text{NO}_2]_{\text{out}} - [\text{N}_2\text{O}]_{\text{out}}}{[\text{NO}]_{\text{in}} - [\text{NO}]_{\text{out}} + [\text{NH}_3]_{\text{in}} - [\text{NH}_3]_{\text{out}}} \times 100$$

3. Results and discussion

3.1. Boosted deNO_x reaction under SO_x environment absorption

XRD results of Ni_{1-x}V_xWO₄ samples in Fig. S1 synthesized by using solid-state reactions demonstrate the single phase of Ni_{0.95}V_{0.05}WO₄, Ni_{0.9}V_{0.1}WO₄, but the impurities phase of peaks exhibit in Ni_{0.85}V_{0.15}WO₄ composition due to the limitation of V solubility in NiWO₄ matrix. We measured deNO_x performance under SO_x using a single phase of Ni_{0.95}V_{0.05}WO₄, Ni_{0.9}V_{0.1}WO₄, and mixed V₂O₅-WO₃ compounds from 100 °C to 300 °C of temperature range for all samples, as shown in Fig. 1a and Fig. S2. The V₂O₅-WO₃ compound exhibited a deteriorated deNO_x performance in the presence of SO_x (see Fig S2). In contrast, Ni_{1-x}V_xWO₄ represented an unusual deNO_x catalytic reaction, as displayed in Fig. 1a. In the absence of SO_x (depicted by open circles),

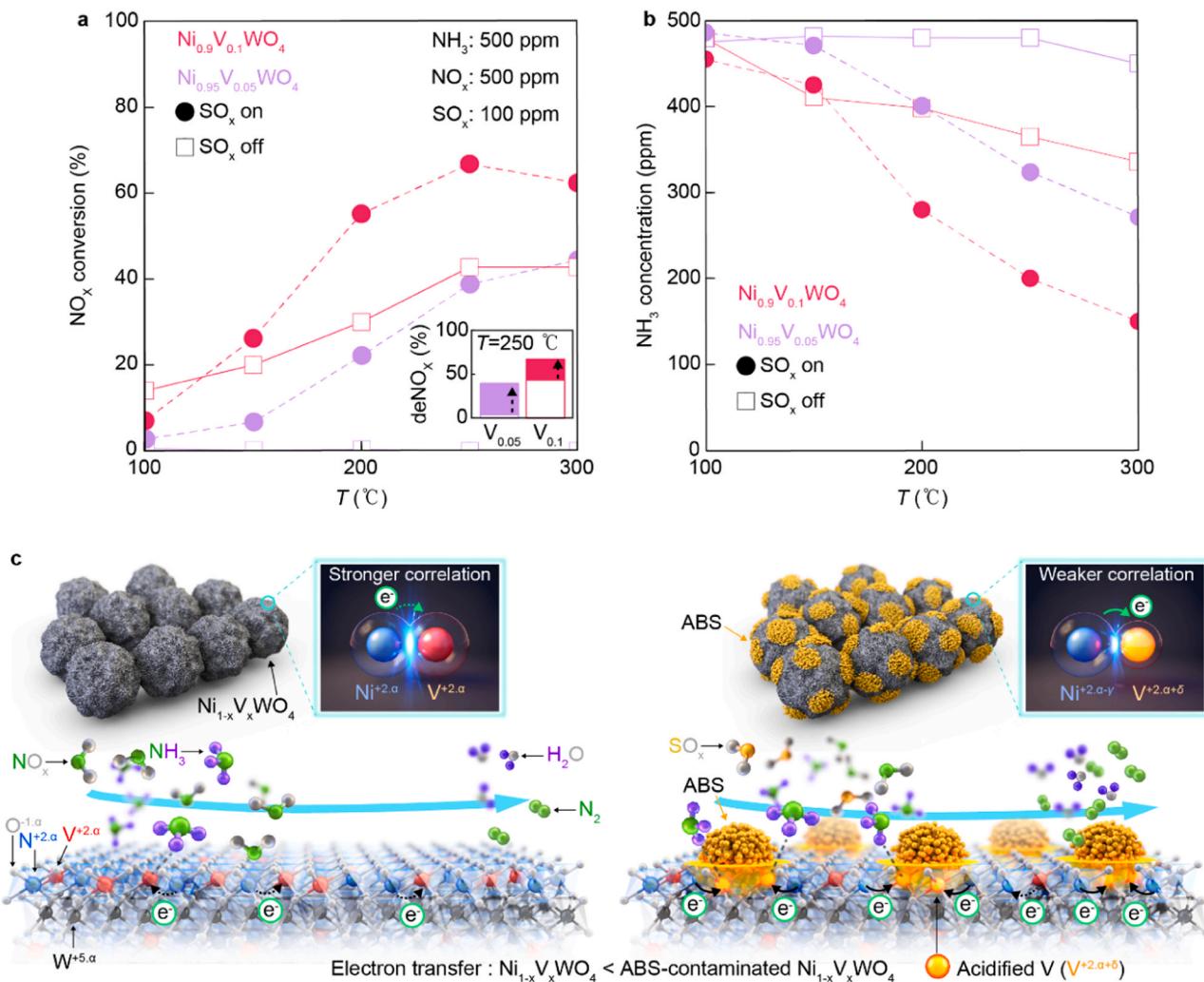


Fig. 1. Boosted deNO_x performance under SO_x environment on Ni_{1-x}V_xWO₄. (a) NO_x conversion performance with SO_x on (closed circle) and SO_x off (open square). The enhanced deNO_x performance at 250 °C is shown in the inset plot. Detailed results on time-dependent deNO_x performance under SO_x can be found in Fig. S3. (b) Plot showing NH₃ concentration changes at different temperatures. Solid squares represent conditions under SO_x, while open squares represent conditions without SO_x. (c) The schematic illustrates the mechanism of boosted deNO_x reaction in the presence of SO_x on ABS-contaminated Ni_{1-x}V_xWO₄ particles. The lower electron transfer on the clean surface (left) and the higher activated electron transfer on the ABS-contaminated Ni_{1-x}V_xWO₄ (right) depend on the correlation strength between Ni (blue atoms) and V (red atoms). The weaker correlation between Ni^{2,α-γ} acidified V (orange atoms, V^{+2,α+δ}) in ABS-contaminated particles exhibits higher NH₃ adsorption than V^{2,x} due to higher activated carrier transfer to V^{+2,α+δ}.

$\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ demonstrated more than a 20% conversion of NO_x around 250 °C, which then increased to approximately 40% conversion up to 300 °C. However, the inactive catalytic response in $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$ can be attributed to its higher band-gap compared to $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$. It is noted that the de NO_x performance was significantly enhanced in the presence of SO_x at 200 – 300 °C (indicated by closed circles). The inset of Fig. 1a shows a more than 20% improvement in the catalytic reaction when $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ is exposed to SO_x poisoning. The NH_3 adsorption on the catalyst surface (Fig. 1b) revealed accordance with the NO_x conversion behavior of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. The substantial reduction in NH_3 concentration under both SO_x and constant SO_x concentration (Fig. S4a) suggests a contradictory higher adsorption of NH_3 without concurrent SO_x adsorption on the $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ surface. The N_2 selectivity (Fig. S4b) exhibited over 95% on both clean and poisoned $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ surfaces. Particularly noteworthy is the low N_2 selectivity and NO_x conversion on the clean $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$, which experienced enhancement under SO_x conditions, suggesting distinct catalytic mechanisms between clean and ABS-contaminated surfaces. This abnormal de NO_x performance observed in this study signifies a distinct catalytic reaction in SCES materials, setting them apart from conventional MOs such as V_2O_5 , MnO , and Cu-zeolites, which typically exhibit degraded NO_x conversion in the presence of SO_x , as demonstrated in numerous reports [8–16]. In conventional SCR catalysts, the catalytic sites are physically obstructed by ABS, and the higher acidified V leads to reduced NO_x conversion due to lower NH_3 absorption, resulting in an unstable reduction/oxidation cycle. However, our report showcases boosted de NO_x performance in ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ SCES materials, achieved by manipulating the V valence state between +2 – +3 through $\text{Ni}^{+2,\alpha}$ in the SCES

NiWO_4 matrix (Fig. 1c). In this system, V predominantly serves as the catalytic site in NiWO_4 for NH_3 adsorption and forms a strong correlation with $\text{Ni}^{+2,\alpha}$, inducing a valence state of $\text{V}^{+2,\alpha}$. In SCES materials with electron hopping paths between cations, the symmetric electron/hole pair of $\text{Ni}^{+2,\alpha}$ and $\text{V}^{+2,\alpha}$ leads to lower carrier transfer in pristine $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, resulting in poor de NO_x performance in terms of NH_3 absorption. Paradoxically, the boosted de NO_x performance with higher NH_3 adsorption on ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ SCES materials arises from increased electron transfer by acidified V, described as $\text{V}^{+2,\alpha+\delta}$. The manipulated $\text{V}^{+2,\alpha+\delta}$ is associated with the preserved crystal structure of ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, which maintains charge neutrality in the presence of ABS. For example, $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ can be expressed as $1-\text{x}\text{Ni}^{+2} + \text{xV}^{+2} + \text{W}^{+6} + 4\text{O}^{-2} = 0$ or $1-\text{x}\text{Ni}^{+3} + \text{xV}^{+3} + \text{W}^{+5} + 4\text{O}^{-2} = 0$. Therefore, ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, with higher acidified form $\text{V}^{+2,\alpha+\delta}$, can be described as $1-\text{x}\text{Ni}^{+2,\alpha-\gamma} + \text{xV}^{+2,\alpha+\delta} + \text{W}^{+5,\alpha} + 4\text{O}^{-2} = 0$ to maintain charge neutrality. As a result, $\text{Ni}^{+2,\alpha-\gamma}$ and $\text{V}^{+2,\alpha+\delta}$ contribute to weaker electron correlation between $\text{Ni}^{+2,\alpha-\gamma}$ and $\text{V}^{+2,\alpha+\delta}$, resulting in increased electron transfer through the asymmetric electron/hole pair between $\text{Ni}^{+2,\alpha-\gamma}$ and $\text{V}^{+2,\alpha+\delta}$. This improved electron transfer to V in ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ leads to higher NH_3 adsorption for a boosted de NO_x reaction, even in the presence of physically blocked catalytic sites due to ABS. In the subsequent section, we will introduce the role of V in the SCES matrix of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, explaining how it maintains a persistent V valence state and enables a stable reduction/oxidation cycle, even in the presence of SO_x .

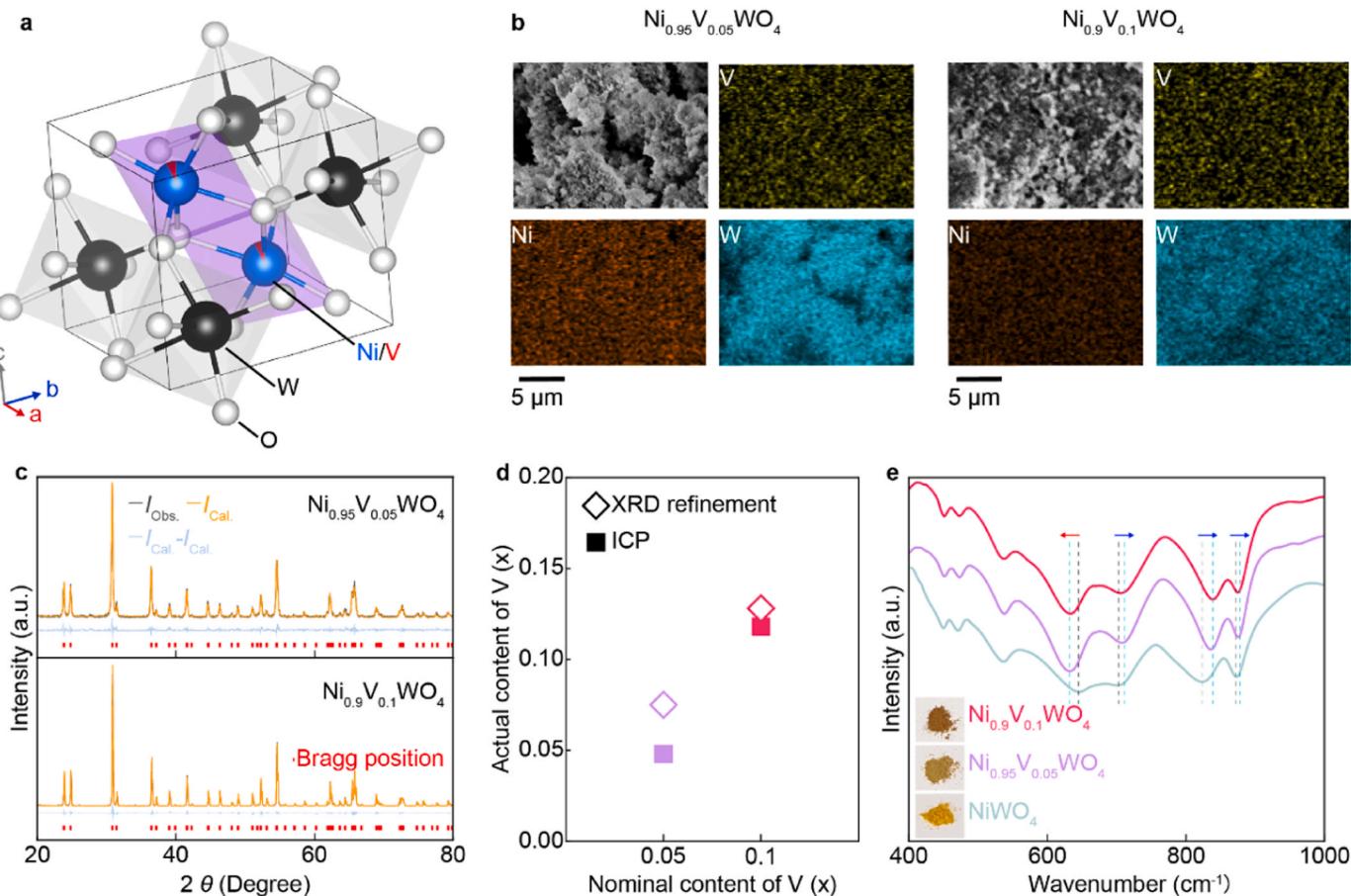


Fig. 2. Structure analysis of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. (a) Schematic illustrating the crystal structure of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. (b) SEM and EDS mapping results of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ powders. (c) XRD Rietveld refinement pattern of powdered $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. (d) Composition analysis from XRD refinement and ICP. (e) FT-IR results of the $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ series at the fingerprint region. The peak shift from NiWO_4 and $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ depicted as black arrow.

3.2. SCES V-doped NiWO₄

The synthesized polycrystalline Ni_{1-x}V_xWO₄ powder, prepared through a solid-state reaction, exhibits the P12/c1 space group crystal structure as depicted in Fig. 2a, and was analyzed by XRD Rietveld refinement. The Ni_{1-x}V_xWO₄ particles show an even distribution of V within them, as observed in Fig. 2b. The structure of Ni_{1-x}V_xWO₄ consists of [NiO₆] and [WO₆] octahedral sublattices, similar to NiWO₄, with the substitutionally doped V occupying the Ni site [34–36]. This positioning of V atoms in the [NiO₆] sites is confirmed by both XRD and XPS data. The Rietveld refinement results derived from powder XRD patterns (Fig. 2c) indicate a single phase of V-doped NiWO₄ composition, revealing a monotonically increasing a-axis lattice parameter with varying V concentrations (detailed parameter results are shown in Table S1). Additionally, the comparison of XRD pattern intensities in Fig. S5 shows the simulated crystal structures: Model 1 of Ni_{0.9}V_{0.1}WO₄ and Model 2 of NiW_{0.9}V_{0.1}O₄, without any modulation of lattice

parameters. Despite sharing the same NiWO₄ Bragg positions in all models, different electron densities for each cation (V, Ni, W) result in distinct intensity ratios between the (0 1 1) and (1 1 0) planes. When V is located at the Ni site, the (0 1 1) plane intensity is higher than (1 1 0), whereas it is the opposite when V atoms are located at the W site. Comparing these intensities to the measured XRD pattern of the powder samples, a higher (0 1 1) intensity is observed, aligning with the characteristics of Model 1 of Ni_{1-x}V_xWO₄. Furthermore, the XPS data in Fig. S6 represent a binding energy of 512.1 eV, corresponding to the maximum peak position of the V 2p_{3/2} for all samples. The deconvolution results indicate a valence state of + 2.α for V. In NiWO₄, the valence states of all cations range from + 2 to + 3 for Ni and + 5 to + 6 for W, while O maintains a - 2 valence state. Considering the cation valence state derived from the deconvolution results of XPS as Ni^{+2.α} and V^{+5.α}, the V^{+2.α} species represent substitutional V atoms in the Ni site within the Ni_{1-x}V_xWO₄ structure. The ionic radius of each cation in the 6-coordination of octahedral structure bonding with O is reported as follows:

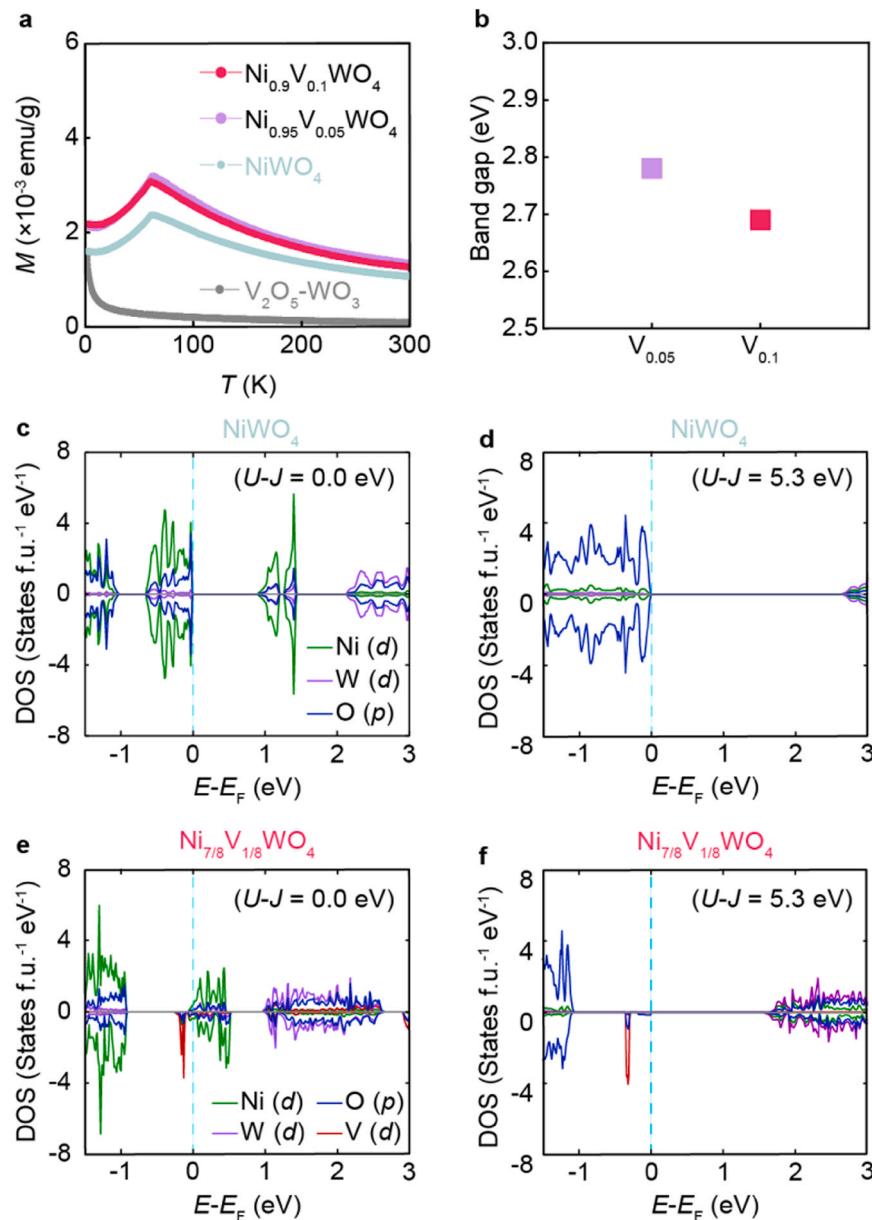


Fig. 3. SCES of Ni_{1-x}V_xWO₄ (a) The antiferromagnetic phase of the Ni_{1-x}V_xWO₄ series and the paramagnetic phase of the V₂O₅-WO₃ compound. (b) The derived band-gap from UV-vis measurements depends on the amount of V. (c-f) PDOS results of NiWO₄ and Ni_{7/8}V_{1/8}WO₄ under different U-J values(U_{eff}). (c) NiWO₄ at $U_{\text{eff}} = 0$ eV. (d) NiWO₄ at $U_{\text{eff}} = 5.3$ eV. (e) Ni_{7/8}V_{1/8}WO₄ at $U_{\text{eff}} = 0$ eV. (f) V_{1/8}Ni_{7/8}WO₄ at $U_{\text{eff}} = 5.3$ eV.

Ni^{+2} 0.69 Å, Ni^{+3} 0.60 – 0.56 Å, W^{+5} 0.62 Å, W^{+6} 0.6 Å, V^{+2} 0.79 Å, and V^{+3} 0.64 Å. These values support the ionic radius of the +2 to +3 valence state of V, corresponding to the Ni^{+2+3} ionic radii when it is substitutionally located in Ni site. The comparison of the V contents derived from XRD refinement and ICP results in Fig. 2d (plotted from Table S2) shows approximately 0.04 and 0.11 V contents from ICP results, and 0.07, 0.13 V contents obtained from XRD refinement. The darker color of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ compared to NiWO_4 samples in the FT-IR results in Fig. 2e implies the role of V as a carrier dopant in the NiWO_4 crystal structure, leading to changes in dipole-dipole interaction, which is reflected in the FT-IR at the fingerprint region [37,38]. The peak shifts (Both of red and blue shift) of FT-IR in Fig. 2e indicate a highly different dipole-dipole interaction between cations when the V atom is doped into NiWO_4 . Despite altered dipole-dipole interaction due to differing electronegativities between $\text{Ni}^{+2,\alpha}$ and $\text{V}^{+2,\alpha}$ in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, strong repulsion between cations is still evident from magnetic properties measurements.

The temperature-dependence magnetization curve (M-T curve) in Fig. 3a demonstrates the antiferromagnetic phase for all $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ compositions, similar to SCES NiWO_4 . The consistent Neel temperature (T_N) across all compositions highlights the strong correlation between cations, such as Ni-Ni and Ni-V. Notably, the magnetic moment of each magnetic cation in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ – 3 – 4 μ_B for Ni^{2+} , ~3.0 μ_B for V^{2+} , and ~3.8 μ_B for V^{3+} – results in a net magnetic moment of zero due to antiferromagnetic ordering. This arises from the strong correlation between magnetic cations. The strong Coulombic repulsion between cations leads to substantial charge gap values, which align with theoretical calculations and validate the measured band gaps via UV-vis. The band gap values of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ (Fig. 3b) are 2.78 eV for $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$

and 2.69 eV for $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$, both of which are lower than the 3.39 eV band gap of the pristine NiWO_4 (Fig. S7), that correlated with the change in carrier transfer behavior by V doping. The modulated band structure of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ is further substantiated by DFT calculations, as shown in Fig. 3c-f. We performed calculations for intrinsic NiWO_4 and $\text{Ni}_{7/8}\text{V}_{1/8}\text{WO}_4$ with effective on-site Coulomb and exchange parameter (U_{eff}) values of 0 and 5.3 eV, signifying the difference between Coulomb parameter (U) and exchange parameter (J). NiWO_4 exhibits a ~2.9 eV band gap when the On-site Coulomb interaction is considered, stemming from the strong electron-electron correlation between Ni (d) and aligning with the SCES properties of NiWO_4 . The ~2.6 eV band gap observed in $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ from UV-vis results is in accordance with DFT+ U outcomes of $\text{Ni}_{7/8}\text{V}_{1/8}\text{WO}_4$, which displays a band gap of 2.7 eV. With an absence of the band gap from $U_{\text{eff}} = 0$ in $\text{Ni}_{7/8}\text{V}_{1/8}\text{WO}_4$, the experimentally synthesized $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ materials demonstrate a strong electron correlation between cations, leading to the emergence of the band gap in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$.

3.3. Modulating weaker electron correlation via acidified V

For a comprehensive understanding of the distinctive deNOx results, we conducted reduction-oxidation chemisorption measurements using H_2 -TPR, NH_3 -TPD, and O_2 -TPO in a clean environment of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ and $\text{V}_2\text{O}_5\text{-WO}_3$ compounds (in Fig. 4a-c). The H_2 -TPR results in Fig. 4a reveal multiple reduction points in V-doped NiWO_4 , which is in contrast to the single peak observed in NiWO_4 and $\text{V}_2\text{O}_5\text{-WO}_3$ compounds at around 680 and 700 °C, respectively. These reduction steps signify the transition of ionized cations to a lower valence state, approaching a metallic state through the H_2 reaction. In the case of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, an

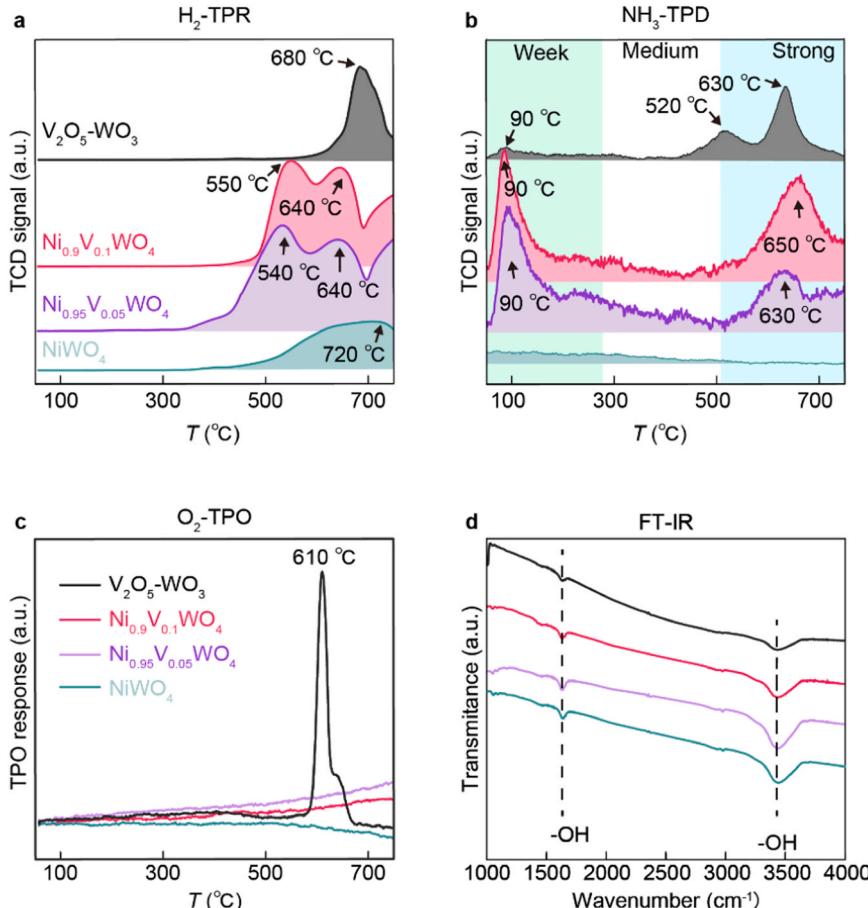


Fig. 4. The chemisorption and FT-IR results of the clean surface of the catalyst sample. (a) H_2 -TPR, (b) NH_3 -TPD, (c) O_2 -TPO results for all samples. (d) FT-IR results of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ series and the $\text{V}_2\text{O}_5\text{-WO}_3$ compound in the $1000 - 40000 \text{ cm}^{-1}$ region with indicated -OH group peaks.

additional reduction step is observed due to the presence of substitutional V. The NH_3 -TPD measurements depicted in Fig. 4b indicate higher NH_3 desorption around 100 °C for $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ samples, along with an additional NH_3 adsorption point around 650 °C. The higher de NO_x

performance of $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ compare to that of $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$ is considered to be related with lower band gap resulting from weakened Coulombic interaction. The lower NH_3 desorption at the medium acid site corresponds to the relatively weak de NO_x performance around

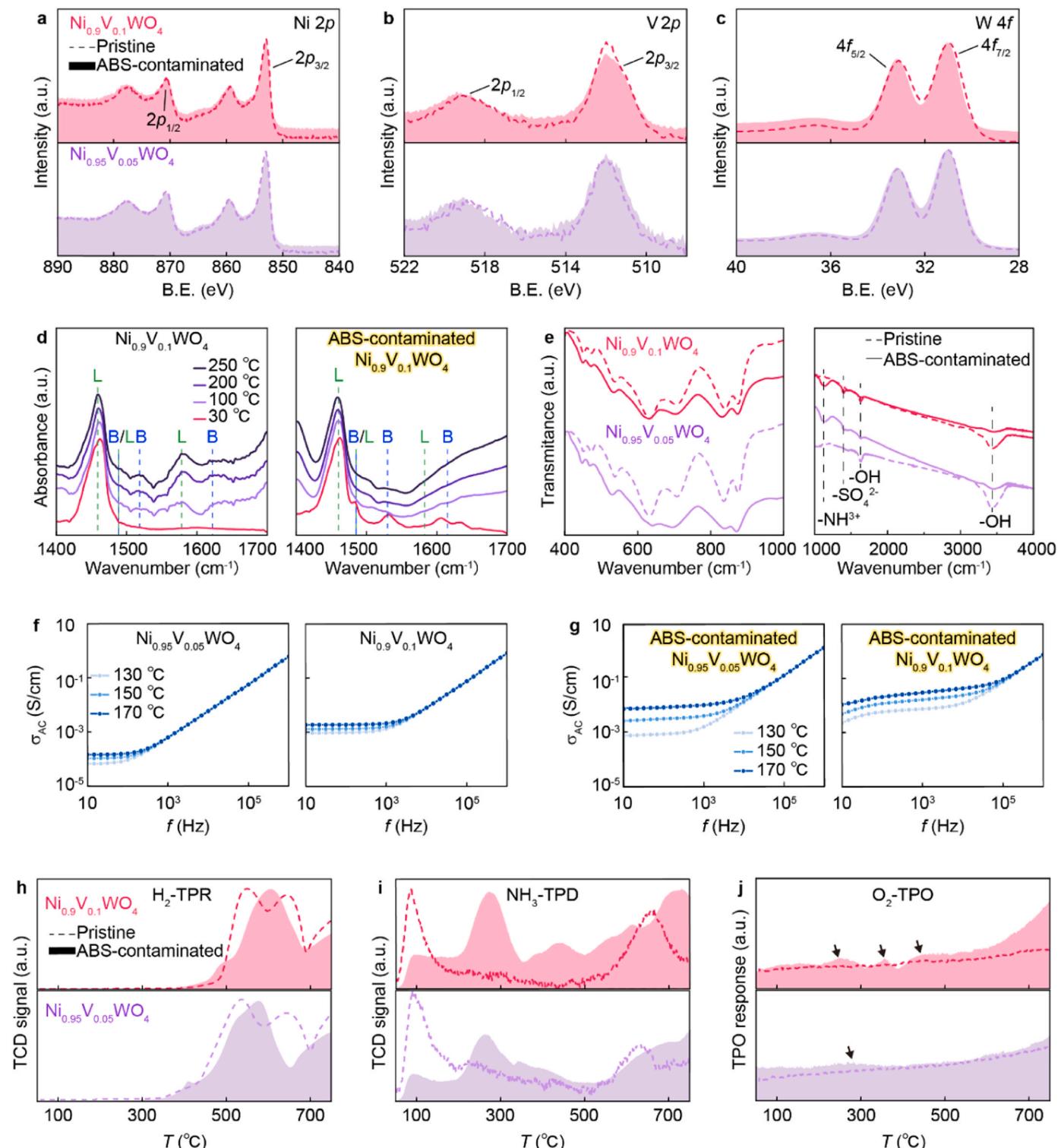


Fig. 5. Weaker electron correlation in ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. (a-c) XPS results with pristine (dotted line) and ABS-contaminated (colored area) for each element such as (a) Ni, (b) V, and (c) W. (Deconvoluted XPS results in noted in Fig. S8.) (d) Temperature dependent acid site measured from Py-FT-IR of $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$, ABS-contaminated $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ (e) FT-IR results of ABS-contaminated (solid line) and pristine (dotted line) $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. (f) and (g) AC conductivity of pristine $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$, $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$, and ABS-contaminated samples at different temperatures. (h-j) Chemisorption results of the ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ samples (colored area) compared with pristine samples (dotted line). (h) H_2 -TPR, (i) NH_3 -TPD, and (j) O_2 -TPO results. The ABS-contaminated $\text{V}_2\text{O}_5\text{-WO}_3$ chemisorption results are in Fig. S10.

200 °C in $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$. However, the O_2 -TPO results in Fig. 4c only show a linear background signal without O_2 desorption peaks in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, indicating a one-way catalytic cycle. In contrast, strong peaks around 610 °C are observed for $\text{V}_2\text{O}_5\text{-WO}_3$ compounds, as previously reported [39]. FT-IR peaks (near 3400 and 1500 cm^{-1}) for hydroxyl (-OH) group were observed both in $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$ and $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ (Fig. 4d), and the fraction of oxygen vacancy, quantified by XPS (Fig. S6), was almost same in these two samples. Hence, the presence of a substitutional V dopant activates the chemical reaction on the NiWO_4 SCES matrix, manifesting in multiple reduction steps. However, the absence of an oxidized step after synthesizing $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ under an air environment indicates that the cation valence state does not exceed $+2.\alpha$ for Ni and V, underscoring the preservation of electron correlation between magnetic cations, as measured by the XPS results (Fig. S6).

To unravel the underlying reason for the boosted deNO_x reaction, even on a catalyst surface obstructed by ABS (Fig. 1a), we performed additional XPS, FT-IR, and chemisorption tests using artificially made ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. The XPS results of the poisoned $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ (displayed in Fig. 5a-c) exhibit similar characteristics to the clean surface samples, indicating the preservation of the valence states of Ni, V, and W in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$.

The Pyrolysis-FT-IR (Py-FT-IR) results for $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$ and $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ at room temperature (shown in Fig. S9) reveal that pristine $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ exclusively exhibits Lewis acid sites. Whereas, ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ includes Brønsted acid sites, originating from the sulfuric acid of ABS on the $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ surface. We measured also the temperature dependence PY-FT-IR of $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ as shown in Fig. 5d. The pristine sample predominantly exhibits Lewis sites, while the ABS-contaminated sample shows mixed Lewis and Brønsted acid sites. On the other hand, the Brønsted site is weakly activated with increasing temperature in the pristine $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$, whereas the Brønsted site is deactivated with increasing temperature in the ABS-contaminated sample. Therefore, the dominant Lewis acid in $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ indicates the NH_3 adsorption on V rather than NH_4^+ adsorption on O, suggesting dominant NH_3 adsorption mechanism via electron transfer between NH_3 and V in NWO₄ SCES matrix for deNO_x measured temperature range. In the FT-IR spectra (Fig. 5e), peak broadening was observed both in $\text{Ni}_{0.95}\text{V}_{0.05}\text{WO}_4$ and $\text{Ni}_{0.9}\text{V}_{0.1}\text{WO}_4$ after ABS contamination. This suggests the change in dipole interaction due to the generation of bonding between ABS and $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. However, the broader peak shape is due to the contamination on the catalyst surface and suggests the relatively weaker electron correlation by lower dipole-dipole interaction between cations. In the 1000 – 4000 cm^{-1} region (Fig. 5f), not only are the -NH₃ and -SO₄ groups presented, but also a noticeable reduction in the -OH group due to the adsorption -NH₃ group instead of -OH as referred to by Brønsted acid site via Py-FT-IR. The weaker electron correlation between Ni and V in SCES $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ is demonstrated by enhanced electron transfer measured, as measured by AC conductivity. The higher AC conductivity observed in ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ compared to pristine $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ (Fig. 5g and h) indicates improved electron transfer due to the asymmetric electron/hole pair of cations in the more acidified environment.

The higher acidified cations in ABS-contaminated samples exhibit different reduction and oxidation points than pristine samples, as shown in Fig. 5h-j (H₂-TPR, NH₃-TPD, and O₂-TPO results). In H₂-TPR (Fig. 5h), a strong single peak around 600 °C is composed of overlapped reduction steps on ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$. The NH₃-TPD (Fig. 5i) shows a distinct trend of NH₃ desorption between the ABS-contaminated sample (solid area) and the pristine sample (dotted line). The higher NH₃ desorption point around 100 °C in the pristine sample becomes weaker, but a larger NH₃ desorption peak of around 250 °C is measured in the ABS-contaminated samples. The large peak of around 250 °C for all samples is related to a combination of the ABS decomposition temperature (~300 °C) and enhanced NH₃ desorption at 200 – 300 °C. Nevertheless, the higher intensity of NH₃ desorption in the overall range

of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ demonstrates the boosted catalytic reaction of $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ compared to the deteriorated NO_x conversion of $\text{V}_2\text{O}_5\text{-WO}_3$ compound under the same SO_x environment (Fig. 3a and Fig. S2). Thus, the reduced -OH group as shown in FT-IR results in Fig. 5e, and increasing NH₃ desorption in medium and strong acid sites suggest that the ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ mainly follows the Lewis acid model, which involves a reduction reaction primarily using electron transfer. The O₂-TPO results (Fig. 5j) imply the mechanism behind the boosted deNO_x performance. The relatively lower O₂-TPO signal of $\text{V}_2\text{O}_5\text{-WO}_3$ in Fig. S10 is related to the weaker reduction/oxidation cycle that leads to deteriorated deNO_x performance (in Fig. S11). However, the emergence of the small peaks on the ABS-contaminated $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ suggests the opening of the reduction/oxidation cycle due to higher carrier transfer between the weaker correlation between $\text{Ni}^{+2,\alpha-\gamma}$ and acidified $\text{V}^{+2,\alpha+\delta}$ as asymmetric electron/hole pair than strong electron correlation between $\text{Ni}^{+2,\alpha}$ and $\text{V}^{+2,\alpha}$ in pristine $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ as described in Fig. 1c.

4. Conclusion

In this study, we introduce a novel V-containing NiWO_4 matrix which exhibits the capability to counteract the degraded denitrification performance in commercial V_2O_5 -based catalysts under the influence of SO_x. This discovery is realized through the strategic control of the V valence state within a strongly correlated electron system. Our design entails substitutional V in NiWO_4 , resulting in a persistent valence state of V as + 2 – + 3, even in the presence of SO_x. This leads to a boosted catalytic reaction with high N₂ selectivity, benefitting from the increased accessibility of catalytic sites due to lower electron correlation, stemming from the higher valence state of acidified V on the ABS-contaminated surface. Our findings reveal that $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$, when contaminated with ABS salt, demonstrates a stable reduction/oxidation cycle and exhibits superior NH₃ absorption, resulting in improved catalytic reactions. Considering the fine-tuning the catalytic particle size to a few nanometers using impregnation and optimizing the appropriate support drive the higher NO_x conversion performance, the $\text{Ni}_{1-x}\text{V}_x\text{WO}_4$ exhibit the potential after optimization to approach toward practical efficiency in relatively high SO_x concentrated environments, such as the oil refining industry. By employing intrinsic cation charge control within a strongly correlated electron system, we not only provide inspiration for the development of selective catalytic reduction materials beyond conventional MOs but also pave the way for a deeper exploration into the underlying mechanisms governing catalytic reactions in strongly correlated electron systems.

CRediT authorship contribution statement

Bang Joonho: Formal analysis, Investigation. **Lee Seung Yong:** Conceptualization, Data curation, Formal analysis, Investigation, Project administration, Supervision, Writing – original draft, Writing – review & editing. **Suh June Won:** Formal analysis, Investigation, Writing – original draft. **Jeong Bo Ra:** Formal analysis, Investigation. **Kim Hong-Dae:** Formal analysis, Investigation. **Lee Jung-Woo:** Formal analysis, Investigation. **Lee Kimoon:** Conceptualization, Data curation, Formal analysis, Writing – original draft, Writing – review & editing. **Choi Myung Sik:** Formal analysis, Investigation. **Jin Changhyun:** Formal analysis, Investigation. **Jeong Si Hoon:** Formal analysis, Investigation. **Park Gi Hyun:** Formal analysis, Investigation. **Sun-Dong Kim:** Formal analysis, Investigation. **Lee Kyu Hyoung:** Conceptualization, Data curation, Formal analysis, Investigation, Project administration, Supervision, Writing – original draft, Writing – review & editing. **Park Jihye:** Investigation, Methodology. **Kim Sung Eun:** Formal analysis, Investigation. **Kim Hak Joo:** Formal analysis, Investigation. **Lee Hye-sung:** Formal analysis, Investigation. **Ji Yunseong:** Formal analysis, Investigation.

Declaration of Competing Interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

Data availability

Data will be made available on request.

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Appendix A. Supporting information

Supplementary data associated with this article can be found in the online version at doi:10.1016/j.apcatb.2023.123540.

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